Low-temperature tapered-fiber probing of diamond nitrogen-vacancy ensembles coupled to GaP microcavities

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Abstract. In this work, we present a platform for testing the device performance of a cavity—emitter system, using an ensemble of emitters and a tapered optical fiber. This method provides high-contrast spectra of the cavity modes, selective detection of emitters coupled to the cavity and an estimate of the device performance in the single-emitter case. Using nitrogen-vacancy (NV) centers in diamond and a GaP optical microcavity, we are able to tune the cavity onto the NV resonance at 10 K, couple the cavity-coupled emission to a tapered fiber and measure the fiber-coupled NV spontaneous emission decay. Theoretically, we show that the fiber-coupled average Purcell factor is 2–3 times greater than that of free-space collection, although due to ensemble averaging it is still a factor of 3 less than the Purcell factor of a single, ideally placed center.

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1. Introduction

Several properties of the negatively charged nitrogen-vacancy center (NV⁻) in diamond make it an attractive candidate as a qubit for quantum information processing (QIP). Firstly, the ground-state electron-spin decoherence time exceeds a millisecond in isotopically purified ¹²C diamond samples [1]. Secondly, an excited-state manifold [2, 3] provides optical access to both initialize and control the electron ground-state spin [4, 5] as well as a way of creating quantum entanglement through photon interference [6]. Finally, hyperfine coupling of the electron spin to either N or ¹³C nuclear spins [7, 8] provides access to a second storage qubit that is needed for quantum protocols based on repeat until success schemes [9, 10].

The majority of NV⁻ experiments reported so far have been performed on NV centers found deep within the diamond substrate using free-space excitation and collection optics. There is now significant motivation to integrate these quantum emitters into optical devices in order to build scalable measurement-based optical quantum networks. To realize these networks, coupling of NV⁻ centers to optical cavities will be necessary in order to enhance emission into the zero-phonon line (ZPL) [11] and for coupling ZPL emission into waveguides for efficient collection. NV-cavity coupling can be obtained by coupling NV centers in diamond nanoparticles to non-diamond microcavities [12–15], by coupling NV centers in single-crystal diamond to non-diamond cavities (hybrid approach) [16, 17] and by fabricating microcavities out of single-crystal diamond (all-diamond approach) [18-21]. Owing to the poor spectral properties of the NV centers found in nano-diamond, the first approach is challenging for scalable optical networks that rely on interference for 'which-path' erasure. Among the singlecrystal diamond approaches, the all-diamond approach has the advantage of a higher optical field strength at the NV site that lies within the cavity structure, and a significant enhancement of the NV emission into the ZPL has already been observed in the case of all-diamond microrings [18]. The hybrid approach, which relies on the coupling of diamond NVs to the evanescent field extending out of the non-diamond cavity, has the potential advantage of additional device functionality provided by the material properties of the waveguide layer. For example, the electro-optic properties of the cavity material could enable switching or cavity tuning capabilities.

A figure of merit for the coupling between a cavity mode and a dipole emitter is the spontaneous emission enhancement (Purcell) factor F_p . For an emitter at position \vec{r} in a monolithic cavity and in resonance with the cavity mode,

$$F_{\rm p} = \frac{3}{4\pi^2} \frac{\lambda_0^3}{n_c^3} \frac{Q}{V} \left| \frac{E(\vec{r})}{\vec{E}(\vec{r}_{\rm max})} \right|^2, \tag{1}$$

in which λ_0^3 is the vacuum wavelength, n_c is the cavity refractive index, Q is the cavity mode quality factor, V is the cavity mode volume, $|\vec{E}(\vec{r})|$ is the electric field strength at the dipole and $|\vec{E}(\vec{r}_{\text{max}})|$ is the maximum electric field strength. There are several key device factors that must be optimized. The optical cavity quality factor Q must be sufficiently large and its mode volume V sufficiently small. The quantum emitter must be coupled spatially to the cavity mode and spectrally on resonance. Finally, in addition to cavity—dipole coupling, the cavity mode must be efficiently coupled to a useful input/output mode (i.e. a waveguide).

When engineering optical devices for QIP applications, device testing becomes prohibitively difficult when all testings must be done on single emitters. This is especially true in the common case where the spectral and spatial properties of the emitter are difficult to control. In this work, we have developed a test platform based on emitter ensembles that is designed to evaluate coupled emitter—cavity performance. This platform is particularly useful in the case of hybrid-type devices, in which the material properties of the waveguide layer may need to be tested before investing the resources necessary for testing single-emitter devices.

In this work, we focus on coupling of an ensemble of near-surface NV⁻ centers in single-crystal diamond to GaP micro-cavities fabricated through photolithographic and dry-etching techniques. We show that it is possible using a tapered fiber to collect emission preferentially from centers that are coupled to the cavity [22, 23]. We are able to deterministically tune the cavity resonance several nanometers onto the NV⁻ ZPL and carry out lifetime measurements using the photoluminescence (PL) collected through the tapered fiber. The lifetime measurements can be used to evaluate NV-device coupling. Although we are experimentally unable to observe a significant reduction in the ensemble lifetime for these particular devices, we demonstrate the feasibility of the testing method and theoretically show that there is a significant advantage in using the tapered fiber over free-space collection in ensemble measurements.

2. Hybrid GaP-diamond cavity fabrication

The tested devices consisted of a GaP microcavity on the top of a diamond pedestal with an ensemble of NVs near the diamond surface (figure 1(a)). GaP has a refractive index of $n_{\text{GaP}} = 3.3$, which is higher than that of diamond ($n_{\text{D}} = 2.4$), and GaP is transparent at 637 nm, the ZPL wavelength. Thus devices made of GaP on diamond can support high-Q modes that couple evanescently to the NV centers near the diamond surface.

Experiments were performed on a commercially available type IIa (110)-oriented diamond chip (Element 6) grown by chemical vapor deposition (CVD) with a nitrogen concentration of [N] < 1 ppm, as specified by the manufacturer. The NV ensemble was created by N⁺ ion implantation at 10 keV (CORE Systems) at a dose of $2 \times 10^{13} \, \mathrm{cm}^{-2}$ followed by a 1h high-temperature anneal at 900 °C in a H₂/Ar forming gas. To maximize the fraction of NV centers in a negatively charged state, the sample was further annealed in an oxygen atmosphere at 465 °C for 2 h [24]. In this sample, there are three mechanisms of NV formation. First, NVs are

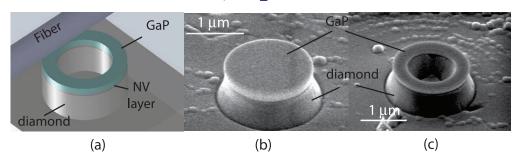


Figure 1. (a) Schematic diagram of tapered-fiber coupling to GaP-diamond hybrid microcavity. (b) Device D1: a 1.5 μ m diameter GaP disc with thickness 250 nm. (c) Device D2: a 1.6 μ m outer diameter GaP ring with thickness 150 nm.

incorporated during the CVD growth process. The density of these NVs is expected to be less than $10^{14} \, \mathrm{cm^{-3}}$ [25] and thus their contribution to the total collected signal can be neglected. A second way in which an NV is formed is when a vacancy created by the implantation process diffuses and is trapped by a native nitrogen during the annealing process. The maximum NV density due to this process is $2 \times 10^{15} \, \mathrm{cm^{-3}}$ based on electron irradiation studies aimed at maximizing the NV⁻ yield in similar CVD material [25]. These NVs are located within the first 200 nm of the surface [26] and have a maximum sheet density of $\sim 4 \times 10^{10} \, \mathrm{cm^{-2}}$. Finally, an NV can form when a vacancy is trapped by implanted nitrogen. This third type of NV is expected to be 14 ± 5 nm from the surface, as estimated using SRIM [27]. The estimated sheet density is $10^{12} \, \mathrm{cm^{-2}}$, assuming a 10% conversion rate of implanted ions into NV⁻, which is typical in our devices. Even for free-space collection, the majority of the NV PL signal is due to the implanted nitrogen. By using a tapered fiber, we are able to further select NVs that are coupled to the cavity. We note that if an electronic-grade CVD diamond substrate ([N] < 1 ppb) were used, only the third type of NV would be present.

The starting material for the GaP microcavities was a commercially available (IQE) wafer consisting of a 250 nm GaP layer on an 800 nm $Al_{0.8}Ga_{0.2}P$ sacrificial layer grown by molecular beam epitaxy. For one set of devices, the original 250 nm thickness was used, while in a second set the GaP layer was thinned by dry etching to 150 nm. The microcavities were defined photolithographically using a mask consisting of 1.5–3 μ m diameter discs. The resist mask (SPR-955) was reflowed on a hotplate at 180 °C and was used as an etch mask in an $Ar/BCl_3/Cl_2$ reactive ion etch (RIE) chemistry. By varying the optical exposure time, it was found that rings could also be produced due to diffraction around the disc mask.

As a further step to facilitate tapered-fiber testing, a $20\,\mu m$ tall, $190\,\mu m$ wide diamond ridge defined by a SiN mask was etched on the diamond surface using an O_2/Ar RIE chemistry. The GaP microcavities were then transferred to the diamond ridge using the probabilistic 'drop-down' method described in [16]. This procedure provides an easy shortcut for testing single devices, but eventually this must be replaced with a wafer-bonding approach before integrated photonic networks can be constructed. After transfer, the devices were etched in an oxygen RIE plasma to create a 600 nm diamond pedestal beneath the GaP discs. This pedestal improves the lateral confinement of the cavity modes, decreasing radiation loss into the diamond substrate [28].

Scanning electron microscope images of the two devices studied in this work are shown in figures 1(b) and (c). Device D1 consisted of a 250 nm thick, $1.5 \mu m$ diameter GaP disc and

device D2 consisted of a 150 nm thick, 280 nm wide ring waveguide with 1.6 μ m outer diameter. These devices were examples of the smallest devices made and had cavity resonances within tuning distance of the NV⁻ ZPL. As for device D2, the simulated electric field intensity of the lowest-order TE mode has a full-width at half-maximum of 180 nm across the waveguide ridge at the NV implantation depth. With an estimated NV sheet density of 10^{12} cm⁻², we estimate 10^4 NVs in the cavity mode volume. Due to inhomogeneous broadening of the NV line, 10% of these NVs will be in resonance with the cavity mode.

3. Tapered-fiber coupling to high-index cavities

A 550 nm \pm 20 nm diameter tapered fiber was used to collect NV PL from the hybrid GaP-diamond cavities. The tapered fiber position was controlled by a piezo stage and contacted to the top or side of the GaP microcavity to collect NV PL, as shown in figure 1(a). Room-temperature transmission measurements were carried out to characterize the fiber-microcavity coupling. Only in the smallest disc devices (sub-2 μ m diameter) could transmission dips be observed, as shown in figure 2(a). Transmission dips ranging from a few percent to a few tens of percent could be attained. The utility of using a tapered fiber for device evaluation depends critically on the collection efficiency, especially in the case of single centers. We have thus estimated the energy decay rate from the cavity mode into the waveguide as a function of the device diameter numerically using coupled mode theory.

We first simulated the uncoupled lowest-order TE and TM cavity modes for disc and ring devices using FDTD (MEEP [29]). The fiber mode was calculated using well-known analytic expressions for a step-index circular waveguide [30]. The fiber diameter was taken to be 550 nm and the fiber index $n_{\rm f} = 1.45$. In [31], an expression for the coupling rate between a cavity mode and fiber is derived using power conservation. Using this formalism, one can show that the total decay rate of energy from the cavity into the fiber is given by

$$\gamma_e = \left| \omega_0 \int_{-l}^{l} dy \int_{A_f} dA \left(n_f^2 - 1 \right) \vec{E}_f(\vec{r}) \vec{E}_c^*(\vec{r}) \right|^2, \tag{2}$$

where \vec{E}_c and \vec{E}_f are the cavity and fiber electric fields, respectively, and $\omega_0 = 2\pi c/(637 \text{ nm})$ is the resonant frequency. The 2D integral is taken over the fiber cross-section A_f and the 1D integral is along the fiber propagation axis y with $\vec{E}_c \cong 0$ at $y = \pm l$. We have assumed that the cavity mode is a standing wave that decays equally into both forward and backward propagating waveguide modes. The cavity field is normalized to unit energy [32],

$$\mu \int_{V} \vec{H}_{c}^{*}(\vec{r}) \cdot \vec{H}_{c}(\vec{r}) dV + \int_{V} \epsilon(\vec{r}) \vec{E}_{c}^{*}(\vec{r}) \cdot \vec{E}_{c}(\vec{r}) dV = 1,$$

and the waveguide field is normalized to unit power,

$$\int_{A_{\mathrm{f}}} (\vec{E}_{\mathrm{f}}^*(\vec{r}) \times \vec{H}_{\mathrm{f}}(\vec{r}) + \vec{E}_{\mathrm{f}}(\vec{r}) \times \vec{H}_{\mathrm{f}}^*(\vec{r})) \cdot \hat{y} \, \mathrm{d}A = \pm 1.$$

 $\vec{H}_{\rm c}(\vec{H}_{\rm f})$ is the cavity (fiber) magnetic field and ϵ is the dielectric constant.

The results of the coupled-mode calculation are shown in figure 2(b) for both ring and disc devices for a fiber in contact with the top of the device (figure 2(c)) and for a fiber in contact with the side of the device (figure 2(d)). Experimentally, there is uncertainty in the fiber-cavity contact position, the extent of the fiber-cavity contact, the fiber diameter and the

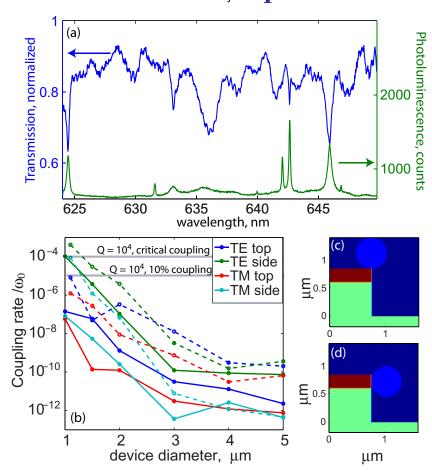


Figure 2. (a) Tapered-fiber NV PL and transmission spectra for device D1. Transmission dips indicating fiber-disc coupling coincide with PL peaks. Broad oscillations in the transmission spectra are believed to be due to etalon effects and coupling to low Q modes during fiber contact. The NV PL spectrum is dominated by the NV⁰ and NV⁻ phonon sideband emission into the cavity modes. (b) Estimation of the coupling rate of disc (solid lines) and ring (dashed lines) devices as a function of device diameter for the lowest-order TE and TM modes near 637 nm. For reference, the coupling rate required for critical coupling and 10% coupling to a device with $Q = 10^4$ is included. Two coupling geometries are calculated. In (c) the fiber is in contact with the top of the device. In (d) it is in contact with the side of the device.

phase of the standing waves. Even with these uncertainties, the simulations do provide some insights into how to achieve the best fiber-device coupling. As the device diameter becomes smaller, it appears easiest to couple to the TE modes from the side of the disc. The ring device in general provides better coupling due to the thinner GaP layer. If we assume a reasonable cavity Q of 10 000, appreciable coupling (the decay rate due to the taper is greater than 10% of the uncoupled decay rate) occurs only for device diameters less than 1.5 μ m. To be able to attain critical coupling in these geometries, the device diameter would need to be sub-micron. Such small devices are desirable for large Purcell factors and could be fabricated using electron-beam

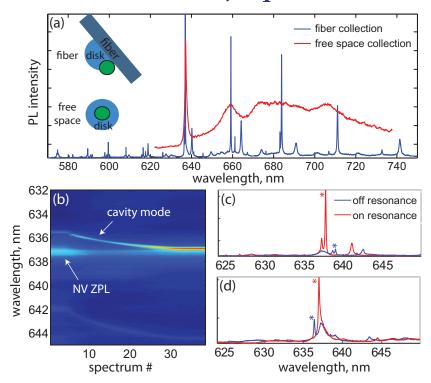


Figure 3. (a) Comparison of the NV spectra with free-space collection and those with tapered-fiber collection in the case of device D1. (b) Tuning spectra in the case of device D2. Cavity-mode tuning with the introduction of xenon gas can be observed. (c,d) NV spectra collected through the tapered fiber for D1 and D2 with the cavity tuned on and off the zero-phonon resonance. The cavity mode of interest is labeled with an asterisk.

lithography. There is, however, a fundamental limit on the minimum device diameter d_{\min} where Q due to the simulated radiation loss becomes comparable to the experimentally observed Q, $Q_{\text{rad}}(d_{\min}) \cong Q_{\text{exp}}$. FTDT calculations show that for GaP-diamond hybrid devices this diameter can be quite small for $Q_{\text{rad}} = 10\,000$: for a 150 nm GaP layer, $d_{\min} \cong 700$ nm, and for a 250 nm layer, $d_{\min} \cong 650$ nm.

4. Fiber collection of the cavity-coupled zero-phonon emission at 10 K

NV PL spectra collected in free-space from the center of disc D1 and collected through a tapered fiber coupled to the whispering-gallery modes of the cavity are shown in figure 3(a). In all PL measurements, the NV centers are excited with 532 nm excitation. In the free-space spectrum, excitation and PL collection are from the top of the disc through a 0.55 numerical aperture objective. The NV⁻ ZPL line is observed at 637 nm with a 1.5 nm inhomogeneous linewidth. This inhomogeneity is generally observed in heavily implanted samples and could be a result of strain introduced during the implantation process. In the tapered fiber spectrum, the disc is excited at its edge and the excitation spot is spatially separated from the tapered-fiber contact position. This is to reduce scatter from uncoupled NVs into the tapered fiber. The sharp cavity modes can clearly be observed over the background PL with a contrast greatly exceeding what

can be achieved in free-space using spatial filtering [16]. In the spatial filtering technique, NV PL is collected through the top objective from the edge of the disc at a location that is spatially separated from the excitation spot. The collection efficiency is extremely variable as it depends on light scattered out of the edge of the disc due to, for example, surface roughness. This results in a much lower collection efficiency when compared to the tapered-fiber technique, despite the larger collection volume. Moreover, experimentally we found significant NV emission at frequencies between the cavity modes. This is presumably due to scattered excitation light and lower *Q* Fabry–Perot-like transverse modes that were not sufficiently filtered using the free-space technique.

Due to variations in device fabrication, it is unlikely that a cavity mode will initially be in resonance with the 637 nm zero-phonon emission. Temperature tuning is not useful in this system because the ZPL becomes phonon broadened at temperatures greater than ~ 15 K [33]. Instead we tune the cavity by injecting xenon gas into the cryostat, which condenses on the microcavity and alters its mode volume [34]. Microdisc resonance tuning up to approximately 3 nm is possible for these GaP devices, which have a free spectral range exceeding 20 nm. It is thus necessary to fabricate many devices to ensure that a subset of devices is within the tuning range. Figure 3(b) depicts a series of PL spectra from device D2 as Xe is continuously leaked into the cryostat. An increase in the PL intensity as the cavity is tuned to the ZPL resonance is observed. A comparison between the on-resonance and off-resonance fiber spectra for D1 and D2 is made in figures 3(c) and (d), showing a marked enhancement of the ZPL collection in the resonant case. Quality factors of 4900 and 3500 were measured for D1 and D2, respectively.

5. Lifetime measurements of cavity-coupled nitrogen-vacancy (NV) centers

The NV-cavity coupling strength can be determined from changes in the spontaneous emission lifetime that occur when the NV ZPL is resonant with the cavity mode. The decay rate for a single NV center prepared in a particular excited state i may be written as

$$\gamma_i = \gamma_0 + F_{p,i} \gamma_{0,ZPL}, \tag{3}$$

where γ_0 is the total uncoupled decay rate including nonradiative channels as well as spontaneous emission through other modes; $\gamma_{0,\text{ZPL}}$ is the zero-phonon spontaneous emission rate in bulk diamond; and $F_{p,i}$ is the Purcell factor. In high-quality diamond samples, typically $\gamma_0 \approx (12\,\text{ns})^{-1}$, but in the present samples we observe $\gamma_0 \approx (8\,\text{ns})^{-1}$, suggesting a strong non-radiative component. We have previously measured $\gamma_{0,\text{ZPL}} \sim 0.03$ of the total NV⁻ photoluminescence intensity including the phonon sidebands, which is consistent with the literature [35]. If $\gamma_{0,\text{ZPL}}$ represents a fraction η of the total uncoupled decay rate γ_0 , then the ratio of the on-resonance lifetime τ_c to the uncoupled lifetime τ_0 would be

$$\frac{\tau_{\rm c}}{\tau_0} = \frac{\gamma_0}{\gamma_0 + F_{{\rm p},i} \gamma_{\rm ZPL}} = \frac{1}{1 + F_{{\rm p},i} \eta}.$$

Using the tapered-fiber collection, we measure the SE decay curve of the cavity-coupled NV ensemble. This measurement, combined with a theoretical consideration of the effects of ensemble averaging, can be used to estimate the spontaneous emission enhancement of a single NV center with a particular position and orientation, as discussed below. Prior to carrying out ensemble lifetime measurements, the cavity was tuned to the ZPL resonance. NV emission was collected through the fiber using the geometry depicted in figure 3(a). PL spectra under

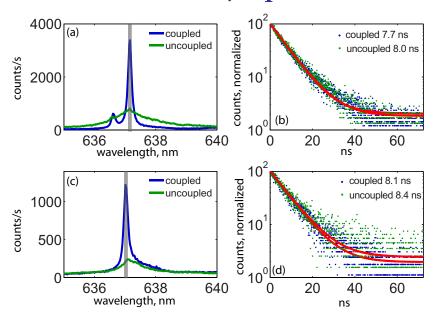


Figure 4. (a,c) PL spectra of coupled and uncoupled NVs in devices D1 and D2. Filter bandwidth of the collected PL for the lifetime measurement is indicated in grey. (b,d) Lifetime measurements of coupled and uncoupled NVs in devices D1 and D2.

continuous-wave excitation of NVs in the disks D1 and ring D2 devices are shown in figures 4(a) and (c). For the lifetime measurements, a green pulsed excitation source was used, based on supercontinuum generation with a Ti-sapphire laser. The excitation source had a bandwidth of 28 nm centered at 520 nm and a repetition rate of 4.75 MHz. The ZPL emission was filtered as depicted by the shaded regions in figures 4(a) and (c). The SE decay curves for devices D1 and D2 were fitted to a single exponential with decay times of 7.66 ± 0.08 ns and 8.08 ± 0.18 ns, respectively (figures 4(b) and (d)). The measurement was repeated on NV centers that were not coupled to the cavity mode. To collect uncoupled emission, the fiber was placed across the center of the device and the NV centers directly under the fiber were excited. As seen from the PL spectra in figures 4(a) and (c), in this excitation/collection geometry the ZPL line is weak and broad and thus shows no features of the cavity mode. Lifetime measurements of uncoupled NVs yielded characteristic decay times of 7.95 ± 0.08 ns and 8.38 ± 0.18 ns for D1 and D2, respectively. We show below that this lifetime reduction is somewhat smaller than what is expected theoretically.

6. Simulated lifetime modification

Next, let us discuss the lifetime modification expected theoretically for a large ensemble of NV centers coupled to the cavity modes of device D2. Each NV center has a number of characteristics that affect its excited-state dynamics, including its position relative to the cavity mode, the orientation of the N–V axis along one of the four (111) axes, the principal axes of symmetry breaking for the two excited orbital states as determined by local strain or electric fields, and the frequency shifts of the optical transitions, again determined by local fields.

Nonradiative decay channels may also be present, including decay through the singlet states (especially from the $m_s = \pm 1$ spin sublevels [36]).

To simplify the discussion, here we neglect the dynamics of the spin sublevels, and consider only the two orbital excited states. Such an approximation is not suitable for a detailed analysis of NV dynamics, but suffices to illustrate the effect of spatial and orientational inhomogeneity on the radiative dynamics. Under this simplification, we can use equation (3) to model the decay rate for a single NV center prepared in a particular excited state i, and we let $\gamma_{0.7PL} = (0.03)(12 \text{ ns})^{-1} = 0.0025 \text{ ns}^{-1}$. The Purcell factor is given by

$$F_{\mathrm{p},i} \approx \frac{3}{4\pi^2} Q \frac{(\lambda_0/n_{\mathrm{c}})^3}{V} \frac{n_{\mathrm{c}}}{n_d} \left| \frac{\hat{\mu}_i \cdot \vec{E}(\vec{r})}{E_{\mathrm{max}}} \right|^2 \frac{\kappa^2}{\kappa^2 + 4\Delta_i^2},\tag{4}$$

which is similar to equation (1) except that we have included the factor of n_c/n_d necessary for the hybrid geometry and also the effect of dipole alignment and spectral detuning. Here, n_d is the diamond refractive index and $\hat{\mu}_i$ is a unit vector parallel to the relevant transition dipole moment. The hybrid-cavity mode volume is given by

$$V = \frac{\int d^3 \vec{r} \epsilon(\vec{r}) |\vec{E}(\vec{r})|^2}{\epsilon(\vec{r}_{\text{max}}) |\vec{E}(\vec{r}_{\text{max}})|^2},$$

in which $\epsilon(\vec{r}_{\text{max}}) = n_{\text{c}}^2$ is the dielectric constant at the location of the field maximum [11]. The NV center has two optical transitions involving the two orbital excited states with dipole moments orthogonal to the (111) N-V axes. The principal axes [37, 38] can be described in terms of an angle β ; for example, in the case of an NV oriented along [1, 1, 1]/ $\sqrt{3}$, the dipole moments are $\mu_1 = \vec{u}_1 \cos \beta + \vec{u}_2 \sin \beta$ and $\mu_2 = -\vec{u}_1 \sin \beta + \vec{u}_2 \cos \beta$, where $\vec{u}_1 = -\vec{u}_1 \sin \beta + \vec{u}_2 \cos \beta$ $[-1, -1, 2]/\sqrt{6}$ and $\vec{u}_2 = [1, -1, 0]/\sqrt{2}$. If the angle β is determined by local fields, then we expect it to be randomly distributed, and here we assume a uniform distribution. It is important to note that we neglect population relaxation between orbital excited states. This assumption is reasonable only for measurements carried out at liquid-helium temperatures [33]. We further assume that the two orbital excited states have the same unmodified decay rate. In general, we must also include the effect of detuning, and here Δ_i is the detuning between the dipole transition frequency and the central frequency of the cavity mode, while $\kappa = \omega_0/Q$ is the cavity linewidth. In the measurement, we detect photoluminescence through a spectral filter of 0.06 nm bandwidth centered at the cavity frequency, and therefore we detect emission only from a subset of NV transitions that are nearly in resonance with the cavity mode. Thus we set $\Delta_i = 0$ for the present calculation.

While our model assumes a simple exponential decay for each NV transition, the ensemble-averaged behavior is non-exponential but can be written as

$$I(t>0) = \int_0^\infty d\zeta \ G(\zeta) e^{-(\gamma_0 + \zeta \gamma_{0,\text{ZPL}})t},\tag{5}$$

where I(t) is the measured PL decay curve and $G(\zeta)$ represents a distribution of NV transitions with various Purcell factors, decaying at various rates, weighted by their relative occurrence and by their excitation and collection efficiencies. For free-space collection, this distribution can be written as

$$G_{\text{f.s.}}(\zeta) \propto \sum_{\vec{r},\vec{\alpha},\beta} \rho(\vec{r},\vec{\alpha},\beta) I_{\text{exc}}(\vec{r},\vec{\alpha},\beta) \, \delta(F_{\text{p}}(\vec{r},\vec{\alpha},\beta) - \zeta). \tag{6}$$

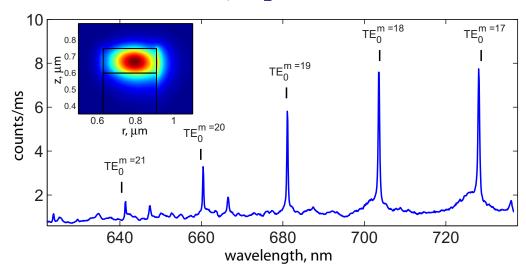


Figure 5. Room-temperature PL spectra collected through the tapered fiber for D2. Observed resonances are in reasonable agreement with simulated modes, which include the effect of dispersion on GaP [39]. A similar agreement can be found for TM₀ modes for a ring with an outer diameter of 1.96 μ m. Inset: simulated mode profile $|E(r, z, \phi = 0)|$ for TE₀^{m=21}.

This expression represents a probability density of Purcell factor values, weighted by the NV density and excitation efficiency. When this is inserted into equation (5), integrating over the delta-function one obtains simply the sum of contributions to the intensity decay curve from all NV centers. We have omitted additional terms that scale the signal intensity by a constant factor, such as collection efficiency, photon emission rate, and spectral density of the NV distribution at the collection wavelength. In equation (6), $\vec{\alpha}$ is the N–V orientation vector, and $\rho(\vec{r}, \vec{\alpha}, \beta)$ is the NV density with respect to position and dipole orientation. For the spatial dependence, we approximate $\rho(z)$ as a Gaussian distribution with respect to depth below the surface, with a mean depth of 15 nm and variance (straggle) of 5 nm. Such a distribution corresponds to a uniform 10 keV nitrogen ion implantation, as estimated using SRIM [27], assuming that the resulting NV centers incorporate only implanted nitrogen and that the implanted nitrogen does not diffuse during annealing. The excitation efficiency $I_{\rm exc}(\vec{r},\vec{\alpha},\beta)$ includes a spatial dependence that is modeled as a diffraction-limited Airy disc pattern corresponding to 532 nm excitation through a 0.55 numerical aperture lens (FWHM ~ 500 nm), centered between the inner and outer edges of the ring structure. The excitation efficiency is also assumed to be proportional to $|\vec{\mu} \cdot E_{\rm exc}|^2$, where the excitation polarization \vec{E} is along [1, 0, 0].

For collection through the tapered fiber, equation (6) must be modified since, ideally, only light emitted into the cavity mode of interest is collected. Thus, we weight by the emission rate into the cavity mode, which is proportional to the Purcell factor,

$$G_{\text{w.g.}}(\zeta) \propto \sum_{\vec{r},\vec{\alpha},\beta} \rho(\vec{r},\vec{\alpha},\beta) I_{\text{exc}}(\vec{r},\vec{\alpha},\beta) F_{\text{p}}(\vec{r},\vec{\alpha},\beta) \delta(F_{\text{p}}(\vec{r},\vec{\alpha},\beta) - \zeta). \tag{7}$$

The lowest-radial order TE cavity field was simulated for the calculation using FDTD (MEEP) software [29]. Reasonably good agreement between the experimental and simulated resonance frequencies could be obtained for a model device with $1.8 \,\mu\text{m}$ outer diameter, as shown in figure 5. Using the parameters given above, setting Q = 3500 and considering a single

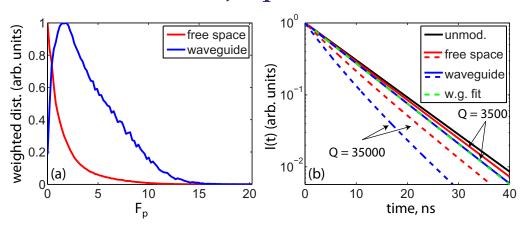


Figure 6. (a) Weighted distribution of the Purcell factor F_p simulated for the D2 microring structure with free-space collection (red) and for collection through a waveguide coupled only to the cavity mode of interest (blue). (b) Simulated PL decay curves for unmodified NV centers with $\gamma_0 = (8.4 \, \text{ns})^{-1}$ (see text), for NV centers in the D2 microring structure detected with free-space collection (red) and for waveguide collection (blue). A single-exponential fit is also shown for the waveguide collection case (green, dashed) with $\tau = 7.74 \, \text{ns}$. Simulated curves for devices with $Q = 35\,000$ are also included for comparison.

standing-wave cavity mode (rather than degenerate counter-propagating modes), we obtain the Purcell factor histograms shown in figure 6(a). For this mode, the maximum expected Purcell factor for an NV 15 nm below the surface and with perfect dipole alignment is $F_{\rm p,max}=13$. However, for free-space collection the weighted average is only $\langle F_{\rm p} \rangle = 1.8$. For collection through the tapered fiber, because we preferentially detect NV centers that are better coupled to the cavity mode, the average increases to $\langle F_{\rm p} \rangle = 4.2$. But even with the tapered fiber, it is clear that the random spatial and angular distributions of dipole moments reduce the mean cavity enhancement by a large amount.

For a more direct comparison with experiment, PL decay curves generated from these distributions are shown in figure 6(b). Here we have assumed $\gamma_0 = (8.4 \, \mathrm{ns})^{-1}$ to match the behavior observed in these heavily implanted samples, and $\gamma_{0,\mathrm{ZPL}} = 0.0025 \, \mathrm{ns}^{-1}$, as discussed above. Although these decay curves do not follow a single-exponential time dependence, because the average decay modification is weak as compared with γ_0 , it would be quite difficult experimentally to detect the deviation from single-exponential behavior caused by variations in F_p . The effective decay lifetimes obtained by fitting the first 40 ns of decay to a single exponential are 8.10 and 7.74 ns for free-space and tapered-fiber collection, respectively. These are approximately equal to those expected from the $\langle F_p \rangle$ values given above: 8.09 and 7.72 ns for free-space and tapered-fiber collection, respectively. Figure 6(b) also includes simulations for a device with $Q=35\,000$. Q values exceeding 25 000 have been observed previously in much larger hybrid GaP-diamond devices [16], and further work needs to be performed to determine the factors that limit Q in the present devices.

The lifetime modification shown in figure 4, which was at the limit of detection, is smaller than that predicted in this simulation, and some likely causes include the presence of an air gap between the GaP ring [40] and the diamond surface, or non-ideal NV distributions. The

simulations show that collection using the tapered fiber provides an important advantage since it selectively filters out NV centers that are poorly coupled to the cavity. Nevertheless, even using the tapered fiber for collection, ensemble averaging reduces the effective Purcell factor by a factor of approximately 3 compared with that expected for an ideally positioned and oriented NV center.

7. Outlook

There is now significant motivation to integrate photonics with quantum systems for quantum communication, quantum information interfaces and quantum information processing. In the final devices, quantum-photonic 'nodes' will consist of single emitters; however, single emitters are challenging to work with when studying and developing the classical photonic networks. Here, a method that combines an ensemble of emitters and tapered-fiber collection is presented that can be used for fast serial testing of a large number of QIP devices.

Experimentally, we showed that tapered-fiber collection provides a way to obtain high-contrast spectra to reliably observe cavity modes. This is because the fiber enables the selective detection of NVs coupled to the cavity. Compared with a free-space collection, the measurement more directly probes the signal that would be collected by an on-chip waveguide, as part of an integrated photonic network. Although not exploited in this work, variable coupling is also possible with the tapered fiber providing a way of optimizing the combined cooperativity parameter that includes both $F_{\rm p}$ and the waveguide–cavity coupling efficiency. Additionally, numerical calculations indicate that for sub-micron GaP–diamond hybrid devices, the cavity energy decay rate into the fiber should be able to exceed the uncoupled decay rate, allowing for efficient photon collection.

The use of NV ensembles provides two main advantages over single centers in device testing. Firstly, the collected photoluminescence can be much greater, allowing for faster testing. Secondly, device characterization does not rely on the nanometer-scale placement of single emitters. Although the devices used to test this platform did not exhibit a significant Purcell enhancement, theoretically we showed that the fiber-coupled average Purcell factor is 2–3 times greater than that of free-space collection. Moreover, if the distribution of emitters is known, the ensemble device performance can also be used to estimate the single-emitter device performance.

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